Product data sheet

Product profile 1.

1.1 General description

The KMA210 is a magnetic angle sensor module. The MagnetoResistive (MR) sensor bridges, the mixed signal Integrated Circuit (IC) and the required capacitances are integrated into a single package.

This angular measurement module KMA210 is pre-programmed, pre-calibrated and therefore, ready to use.

The KMA210 allows user-specific adjustments of angular range, zero angle and clamping voltages. The settings are stored permanently in a non-volatile memory.

1.2 Features and benefits

- High precision sensor for magnetic angular measurement
- Single package sensor module with integrated filters for improved ElectroMagnetic Compatibility (EMC)
- Automotive qualified in accordance with
 Overvoltage protection up to 16 V AEC-Q100 Rev-G
- Programmable user adjustments, including zero angle and angular range
- Fail-safe non-volatile memory with write User-programmable 32-bit identifier protection using lock bit
- Independent from magnetic field strength above 35 kA/m
- Ready to use without external components

- High temperature range up to 160 °C
- Ratiometric analog output voltage
- Programming via One-Wire Interface (OWI)
- Magnet-loss, power-loss and broken bond wire detection
- Factory calibrated



KMA210 NXP Semiconductors

Programmable angle sensor

Pinning information

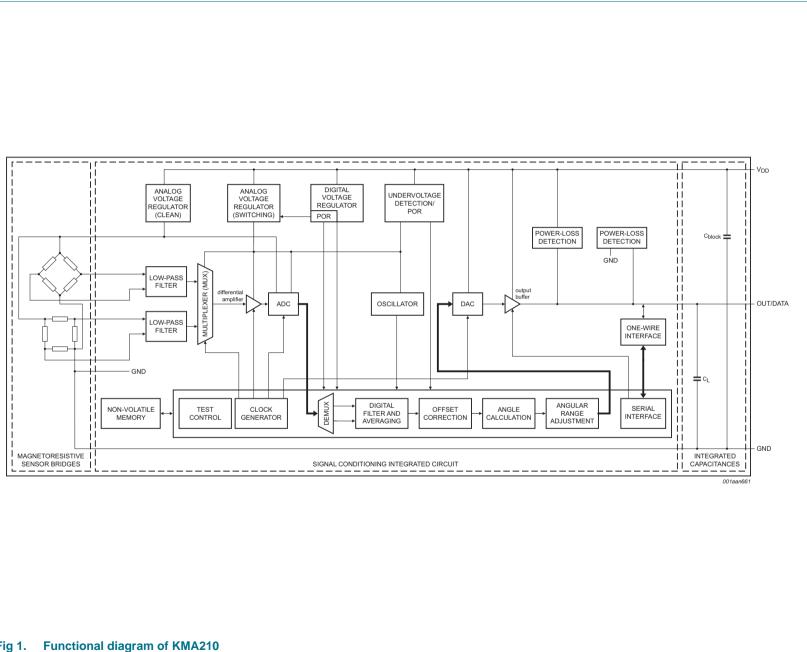
Table	1. Pinning		
Pin	Symbol	Description	Simplified outline
1	V_{DD}	supply voltage	
2	GND	ground	
3	OUT/DATA	analog output or data interface	

3. Ordering information

Table 2. **Ordering information**

Type number	Package						
	Name	Description	Version				
KMA210	-	plastic single-ended multi-chip package; 6 interconnections; 3 in-line leads	SOT1288				

Functional diagram



All information provided in this document is subject to legal disclain

© NXP B.V. 2011. All rights reser

Programmable angle sensor

5. Functional description

The KMA210 amplifies two orthogonal differential signals from MR sensor bridges and converts them into the digital domain. The angle is calculated using the COordinate Rotation Digital Computer (CORDIC) algorithm. After a digital-to-analog conversion the analog signal is provided to the output as a linear representation of the angular value. Zero angle, clamping voltages and angular range are programmable. In addition, two 16-bit registers are available for customer purposes, such as sample identification.

The KMA210 comprises a Cyclic Redundancy Check (CRC) and an Error Detection and Correction (EDC), as well as magnet-loss and broken bond wire detection to ensure a fail-safe operation. A power-loss detection circuit pulls the analog output to the remaining connection, if either the supply voltage or the ground line of the mixed signal IC is interrupted.

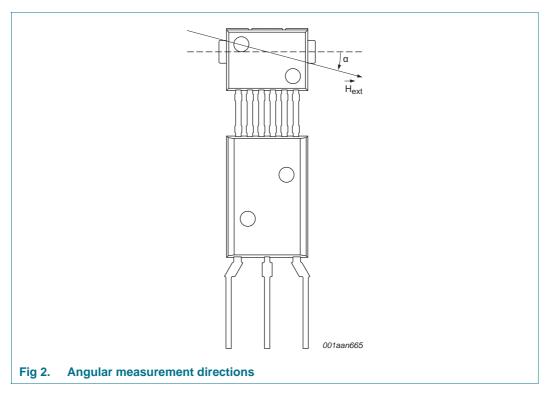
After multiplexing the two MR Wheatstone bridge signals and their successive amplification, the signal is converted into the digital domain by an Analog-to-Digital Converter (ADC). Further processing is done within an on-chip state machine. This includes offset cancellation, calculation of the mechanical angle using the CORDIC algorithm, as well as zero angle and angular range adjustment. The internal Digital-to-Analog Converter (DAC) and the analog output stage are used for conversion of the angle information into an analog output voltage, which is ratiometric to the supply voltage.

The configuration parameters are stored in a user-programmable non-volatile memory. The OWI (accessible using pin OUT/DATA) is used for accessing the memory. In order to protect the memory content a lock bit can be set. After locking the non-volatile memory, its content cannot be changed anymore.

5.1 Angular measurement directions

The differential signals of the MR sensor bridges depend only on the direction of the external magnetic field strength H_{ext} , which is applied parallel to the plane of the sensor. In order to obtain a correct output signal, the minimum saturation field strength has to be exceeded.

Programmable angle sensor



Since the Anisotropic MR (AMR) effect is periodic over 180°, the sensor output is also 180°-periodic, where the angle is calculated relative to a freely programmable zero angle. The dashed line indicates the mechanical zero degree position.

6. Analog output

The KMA210 provides one analog output signal on pin OUT/DATA. The measured angle α is converted linearly into a value, which is ratiometric to the supply voltage V_{DD} . Either a positive or a negative slope is provided for this purpose.

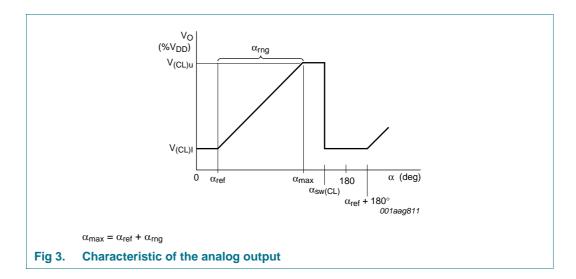
<u>Table 3</u> describes the analog output behavior for a positive slope. If for example, a magnetic field angle, above the programmed maximum angle α_{max} , but below the clamp switch angle $\alpha_{sw(CL)}$ is applied to the sensor, then analog output is set to the upper clamping voltage. If the magnetic field angle is larger than the clamp switch angle, the analog output switches from upper to lower clamping voltage. In the case of a negative slope, the clamping voltages are changed.

Table 3. Analog output behavior for a positive slope

Magnetic field angle	Analog output
$\alpha_{\text{max}} < \alpha < \alpha_{\text{sw(CL)}}$	$V_{(CL)u}$
$\alpha_{\rm SW(CL)} < \alpha < \alpha_{\rm ref} + 180^{\circ}$	$V_{(CL)I}$

The analog output voltage range encodes both angular and diagnostic information. A valid angle value is between the upper and lower clamping voltage. If the analog output is in the diagnostic range, that is below 4 $\rm \%V_{DD}$ or above 96 $\rm \%V_{DD}$, an error condition has been detected. The analog output repeats every 180°.

Programmable angle sensor



7. Diagnostic features

The KMA210 provides several diagnostic features:

7.1 CRC and EDC supervision

The KMA210 includes a supervision of the programmed data. At power-on, a CRC of the non-volatile memory is performed. Furthermore the memory is protected against bit errors. Every 16-bit data word is saved internally as a 22-bit word for this purpose. The protection logic corrects any single-bit error in a data word, while the sensor continues in normal operation mode. Double-bit errors per word will be detected and switches the device into diagnostic mode.

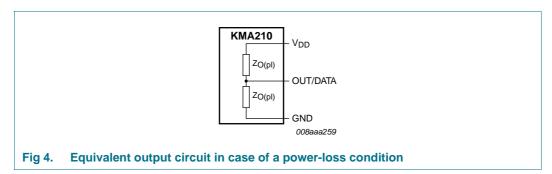
7.2 Magnet-loss detection

If the applied magnetic field strength is not sufficient, the KMA210 can raise a diagnostic condition. In order to enter the diagnostic mode, due to magnet-loss, the detection has to be enabled first. The device can be programmed into active diagnostic mode, where the output is driven below 4 $\%V_{DD}$ or above 96 $\%V_{DD}$.

7.3 Power-loss detection

The power-loss detection circuit enables the detection of an interrupted supply or ground line of the mixed signal IC in normal operation mode up to the maximum operating supply voltage. In the case of a power-loss condition, two internal switches in the sensor are closed, connecting the pin of the analog output to the supply voltage and the ground pins.

Programmable angle sensor



<u>Table 4</u> describes the power-loss behavior and gives the resulting output voltage depending on the interrupted supply or ground line and the load resistance.

Table 4. Power-loss behavior

Load resistance	Interrupted supply line	Interrupted ground line
$R_{L(ext)} > 5 \text{ k}\Omega$	$V_O \le 4 \% V_{DD}$	$V_O \ge 96 \%V_{DD}$

7.4 Broken bond wire detection

The broken bond wire detection circuit enables the detection of an interrupted supply or ground line of the MR sensor bridge. In the case of a broken bond wire the device goes into diagnostic mode and a status bit is set.

7.5 Low supply voltage detection and overvoltage protection

If the supply voltage is below the switch-off threshold voltage, a status bit is set and the device goes into diagnostic mode. If the supply voltage is above the overvoltage switch-on threshold voltage, the device enters diagnostic mode. <u>Table 5</u> describes the system behavior depending on the voltage range of the supply voltage.

Table 5. System behavior

Supply voltage	State	Description
0 V to \cong 1.8 V	start-up power	The output buffer drives an active LOW or is powered down, but the switches of the power-loss detection circuit are not fully opened and set the output to a level between ground and half the supply voltage.
\cong 1.8 V to V_{POR}	power-on reset	The power-loss charge pump is fully operational and turns the switches of the detection circuit off. The output buffer drives an active LOW and sets the output to the lower diagnostic level. During the reset phase all circuits are in reset and/or Power-down mode.
V_{POR} to $V_{th(on)}$ or $V_{th(off)}$	initialization	The digital core and the oscillator are active. After reset the content of the non-volatile memory is copied into the shadow registers. The output buffer drives an active LOW and sets the output to the lower diagnostic level.
$V_{th(on)}$ or $V_{th(off)}$ to minimum V_{DD}	functional operation	All analog circuits are active and the measured angle is available at the analog output. Not all parameters are within the specified limits.

Programmable angle sensor

Table 5. System behavior ...continued

Supply voltage	State	Description
Minimum V_{DD} to maximum V_{DD}	normal operation	All analog circuits are active and the measured angle is available at the analog output. All parameters are within the specified limits.
$\begin{array}{c} \text{Maximum V}_{\text{DD}} \text{ to} \\ \text{V}_{\text{th(ov)}} \end{array}$	functional operation	All analog circuits are active and the measured angle is available at the analog output. Not all parameters are within the specified limits.
V _{th(ov)} to 16 V	overvoltage	The digital core and the oscillator are active but all other circuits are in Power-down mode. The output is set to the lower diagnostic level.

<u>Table 6</u> describes the diagnostic behavior and the resulting output voltage depending on the error case. Furthermore the duration and termination condition to enter and leave the diagnostic mode are given, respectively.

Table 6. Diagnostic behavior

Diagnostic condition	Duration	Analog output	Termination condition
Low voltage	1 μs < t < 10 μs	\leq 4 % V_{DD}	functional or normal operation
Overvoltage	1 μs < t < 10 μs	\leq 4 % V_{DD}	functional or normal operation
Checksum error	n/a	$\leq 4~\%V_{DD}~or \geq 96~\%V_{DD}^{\mbox{\scriptsize $\underline{\tiny [2]}$}}$	power-on reset[1]
Double-bit error	n/a	$\leq 4~\%V_{DD}~or \geq 96~\%V_{DD}^{\cite{2}}$	power-on reset[1]
Magnet-loss	0.5 ms < t < 6 ms	$\leq 4~\%V_{DD}~or \geq 96~\%V_{DD}^{\hbox{\scriptsize [2]}}$	magnet present[1]
Power-loss	\leq 2 ms	$\leq 4~\%V_{DD}~or \geq 96~\%V_{DD}^{\cline{2}}$	power-on reset
Broken bond wire	0.2 ms < t < 1 ms	$\leq 4~\%V_{DD}~or \geq 96~\%V_{DD}^{\cline{2}}$	power-on reset[1]

^[1] Status bit stays set in command register until power-on reset.

8. Limiting values

Table 7. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{DD}	supply voltage		-0.3	+16	V
Vo	output voltage		-0.3	+16	V
$V_{O(ov)}$	overvoltage output voltage	T _{amb} < 140 °C [1] at t < 1 h	$V_{th(ov)}$	16	V
l _r	reverse current	T _{amb} < 70 °C	-	150	mA
T _{amb}	ambient temperature		-40	+160	°C
T _{amb(pr)}	programming ambient temperature		10	70	°C
T _{stg}	storage temperature		-40	+125	°C
Non-volatile	e memory				
t _{ret(D)}	data retention time	T _{amb} = 50 °C	17	-	year
$N_{\text{endu}(W_ER)}$	write or erase endurance	T _{amb(pr)} = 70 °C	100	-	cycle

^[1] Overvoltage on analog output and supply within the specified operating voltage range.

^[2] Depending on the diagnostic level setting.

Programmable angle sensor

9. Recommended operating conditions

Table 8. Operating conditions

In a homogenous magnetic field.

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V_{DD}	supply voltage		<u>[1]</u>	4.5	5.0	5.5	V
T _{amb}	ambient temperature			-40	-	+160	°C
T _{amb(pr)}	programming ambient temperature			10	-	70	°C
C _{L(ext)}	external load capacitance		[1][2]	0	-	22	nF
			[2][3]	0	-	6.8	nF
R _{L(ext)}	external load resistance		[4]	5	-	∞	kΩ
H _{ext}	external magnetic field strength			35	-	-	kA/m

^[1] Normal operation mode.

10. Thermal characteristics

Table 9. Thermal characteristics

Symbol	Parameter	Conditions	Тур	Unit
$R_{th(j-a)}$	thermal resistance from junction to ambient		145	K/W

11. Characteristics

Table 10. Supply current

Characteristics are valid for the operating conditions, as specified in Section 9.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I_{DD}	supply current	[1][2	2 5	-	10.5	mA
		[3][4	<u> </u>	-	13	mA
$I_{\text{off(ov)}}$	overvoltage switch-off current	<u>[5</u>	<u>il</u> -	-	6	mA

^[1] Normal operation and diagnostic mode excluding overvoltage and undervoltage within the specified operating supply voltage range.

^[2] Between ground and analog output.

^[3] Command mode.

^[4] Power-loss detection is only possible with a load resistance within the specified range connected to the supply or ground line.

^[2] Without load current at the analog output.

^[3] Normal operation and diagnostic mode over full voltage range up to limiting supply voltage at steady state.

^[4] With minimum load resistance at the analog output.

^[5] Diagnostic mode for a supply voltage above the overvoltage threshold voltage up to the limiting supply voltage.

Programmable angle sensor

Table 11. Power-on resetCharacteristics are valid for the operating conditions, as specified in <u>Section 9</u>.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$V_{th(on)} \\$	switch-on threshold voltage	analog output switches on, if $V_{DD} > V_{th(on)}$	-	4.30	4.45	V
$V_{\text{th(off)}}$	switch-off threshold voltage	analog output switches off, if $V_{DD} < V_{th(off)}$	3.90	4.10	-	V
V _{hys}	hysteresis voltage	$V_{hys} = V_{th(on)} - V_{th(off)}$	0.1	0.2	-	V
V_{POR}	power-on reset voltage	IC is initialized	-	3.3	3.6	V
$V_{\text{th(ov)}}$	overvoltage threshold voltage	analog output switches off, if $V_{DD} > V_{th(ov)}$	6.5	7.5	8.0	V
V _{hys(ov)}	overvoltage hysteresis voltage		0.1	0.3	-	V

Table 12. Module performance

Characteristics are valid for the operating conditions, as specified in Section 9.

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
α_{res}	angle resolution		<u>[1]</u>	-	-	0.04	deg
α_{max}	maximum angle	programmable angular range for $V_{(CL)u} - V_{(CL)I} \ge 80 \ \%V_{DD}$	[2]	5	-	180	deg
α_{ref}	reference angle	programmable zero angle	[2]	0	-	180	deg
$V_{O(nom)}$	nominal output voltage	at full supply operating range		5	-	95	$%V_{DD}$
$V_{O(udr)}$	upper diagnostic range output voltage		[3][4][5]	96	-	100	$%V_{DD}$
$V_{O(Idr)}$	lower diagnostic range output voltage		[3][4][5]	0	-	4	%V _{DD}
$V_{(CL)u}$	upper clamping voltage		[4][5][6]	40	-	95	$%V_{DD}$
V _{(CL)I}	lower clamping voltage		[4][5][6]	5	-	30.5	$%V_{DD}$
$\Delta V_{(CL)}$	clamping voltage variation	deviation from programmed value	[4][5]	-0.3	-	+0.3	$%V_{DD}$
$V_{n(o)(RMS)}$	RMS output noise voltage	equivalent power noise	[1][4]	-	0.4	2.5	mV
$\Delta \phi_{lin}$	linearity error	temperature range –40 °C to +160 °C	[4][7]	-1.2	-	+1.2	deg
		temperature range -40 °C to +140 °C	[4][7]	–1	-	+1	deg
$\Delta \phi_{\text{temp}}$	temperature drift error	temperature range -40 °C to +160 °C	[1][4][7] [8]	-	-	0.8	deg
		temperature range -40 °C to +140 °C	[1][4][7] [8]	-	-	0.65	deg
$\Delta \phi_{\text{temp}} _{\text{RT}}$	temperature drift error at room temperature	temperature range -40 °C to +160 °C	[7][8][9]	-	-	0.65	deg
		temperature range -40 °C to +140 °C	[7][8][9]	-	-	0.55	deg
$\Delta \phi_{hys}$	hysteresis error	referred to input	[4][7]	-	-	0.09	deg
$\Delta \phi_{\mu lin}$	microlinearity error	referred to input	[4][7]	-0.1	-	+0.1	deg

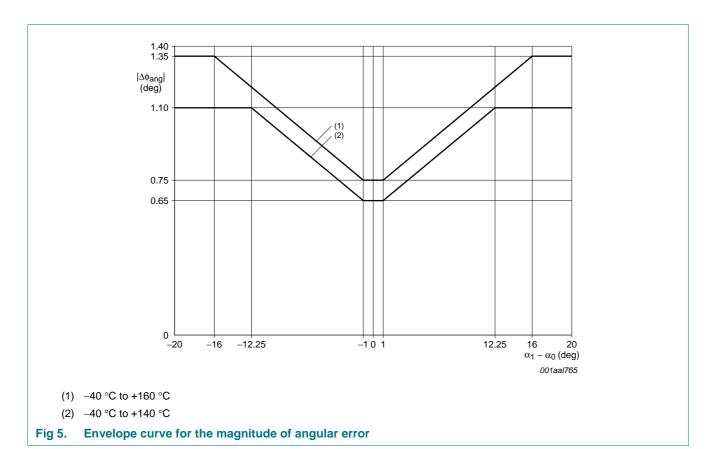
Programmable angle sensor

 Table 12.
 Module performance ...continued

Characteristics are valid for the operating conditions, as specified in Section 9.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$\Delta \phi_{ ext{ang}}$	angular error	temperature range -40 °C to +160 °C	[4][7] -1.35 [10]	-	+1.35	deg
		temperature range -40 °C to +140 °C	[4][7] -1.1 [10]	-	+1.1	deg
m _{ang}	slope of angular error		[4][7] _ [10]	-	0.04	deg/deg
$Z_{O(pl)}$	power-loss output impedance	impedance to remaining supply line in case of lost supply voltage or lost ground	-	-	210	Ω

- [1] At a nominal output voltage between 5 %V_{DD} and 95 %V_{DD} and a maximum angle of α_{max} = 180°.
- [2] In steps of resolution < 0.022°.
- [3] Activation is dependent on the programmed diagnostic mode.
- [4] At a low-pass filtered analog output with a cut-off frequency of 0.7 kHz.
- [5] Settling to these values is limited by 0.7 kHz low-pass filtering of analog output.
- [6] In steps of 0.02 %V_{DD}.
- [7] Definition of errors is given in Section 12.
- [8] Based on a 3σ standard deviation.
- [9] Room temperature is given for an ambient temperature of 25 $^{\circ}$ C.
- [10] Graph of angular error is shown in Figure 5.



KMA210

Programmable angle sensor

Table 13. Dynamics

Characteristics are valid for the operating conditions, as specified in Section 9.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
t _{on}	turn-on time	until first valid result	-	-	5	ms
f _{upd}	update frequency		2.4	3.125	-	kHz
t _s	settling time	after an ideal mechanical angle step of 45°, until 90 % of the final value is reached	-	-	1.8	ms
t _{cmd(ent)}	enter command mode time	after power on	20	-	30	ms
t _{rec(ov)}	overvoltage recovery time	after overvoltage	-	-	4	ms

Table 14. Digital interface

Characteristics are valid for the operating conditions, as specified in Section 9.

Conditions $I_{O} = 2 \text{ mA}$ $I_{O} = 2 \text{ mA}$ absolute value for overdriving	Min 80 - 80 -	Typ	- 20	World WVDD WVDD
$I_O = 2 \text{ mA}$	- 80	-	20	%V _{DD}
$I_O = 2 \text{ mA}$	80	-	-	
$I_O = 2 \text{ mA}$		-	-	20 A DD
	-	-		
absolute value for overdriving			20	$%V_{DD}$
the output buffer	-	-	20	mA
LOW level before rising edge	5	-	-	μS
HIGH level before falling edge	5	-	-	μS
minimum period may be limited by the load capacitance	10	-	100	μS
deviation between received clock and sent clock	0.8T _{bit}	1T _{bit}	1.2T _{bit}	μS
	$0.175T_{bit}$	$0.25T_{bit}$	$0.375T_{bit}$	μS
	0.625T _{bit}	$0.75T_{bit}$	0.825T _{bit}	μS
communication reset guaranteed after maximum t _{to}	-	-	220	μS
duration of LOW level for slave takeover	1	-	5	μS
duration of LOW level for master takeover	0T _{bit}	-	0.5T _{bit}	μS
for a single memory address	20	-	-	ms
waiting time after enabling the non-volatile memory charge pump clock	1	-	-	ms
	the output buffer LOW level before rising edge HIGH level before falling edge minimum period may be limited by the load capacitance deviation between received clock and sent clock communication reset guaranteed after maximum t _{to} duration of LOW level for slave takeover duration of LOW level for master takeover for a single memory address waiting time after enabling the non-volatile memory charge	the output buffer LOW level before rising edge 5 HIGH level before falling edge 5 minimum period may be limited by the load capacitance deviation between received clock and sent clock 0.175T _{bit} communication reset guaranteed after maximum t _{to} - duration of LOW level for slave takeover duration of LOW level for master takeover for a single memory address 20 waiting time after enabling the non-volatile memory charge 10 HIGH level 5 0.8T _{bit} 0.625T _{bit} - 0.625T _{bit} 1	the output buffer LOW level before rising edge 5 - HIGH level before falling edge 5 - minimum period may be limited by the load capacitance deviation between received clock and sent clock 0.175T _{bit} 0.25T _{bit} 0.625T _{bit} 0.75T _{bit} communication reset guaranteed after maximum t _{to} duration of LOW level for slave takeover duration of LOW level for master takeover for a single memory address waiting time after enabling the non-volatile memory charge	the output buffer LOW level before rising edge 5

Table 15. Internal capacitances

Characteristics are valid for the operating conditions, as specified in Section 9.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
C _{block}	blocking capacitance		<u>[1]</u> 25	47	75	nF
C _L	load capacitance		<u>11</u> 1.1	2.2	3.3	nF

^[1] Measured at 1 MHz.

All information provided in this document is subject to legal disclaimers.

© NXP B.V. 2011. All rights reserved.

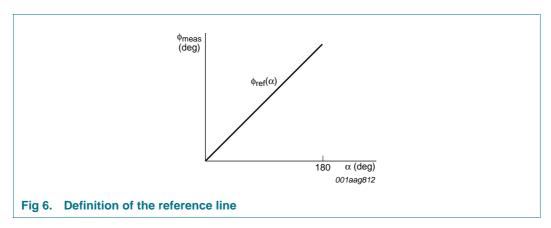
KMA210

Programmable angle sensor

12. Definition of errors

12.1 General

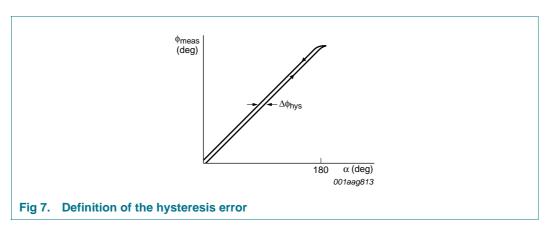
Angular measurement errors by the KMA210 result from linearity errors, temperature drift errors and hysteresis errors. Figure 6 shows the output signal of an ideal sensor, where the measured angle ϕ_{meas} corresponds ideally to the magnetic field angle α . This curve will further be denoted as angle reference line $\phi_{ref}(\alpha)$ with a slope of 0.5 %V_{DD}/degree.



The angular range is set to α_{max} = 180° and the clamping voltages are programmed to $V_{(CL)I}$ = 5 % V_{DD} and $V_{(CL)u}$ = 95 % V_{DD} for a valid definition of errors.

12.2 Hysteresis error

The hysteresis error $\Delta\phi_{hys}$ is defined as the maximum difference between the angles, given by the device output when performing a positive (clockwise) rotation and negative (counter clockwise) rotation over an angular range of 180°, measured at a constant temperature.



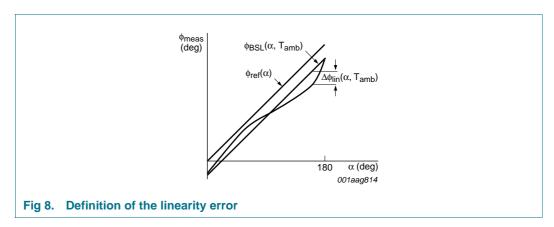
Equation 1 gives the mathematical description for the hysteresis value $\Delta \phi_{hys}$:

$$\Delta \phi_{hys}(\alpha) = \left| \phi_{meas}(\alpha \to 180^{\circ}) - \phi_{meas}(\alpha \to 0^{\circ}) \right| \tag{1}$$

Programmable angle sensor

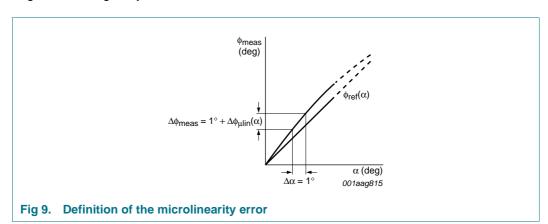
12.3 Linearity error

The KMA210 output signal deviation from a best straight line ϕ_{BSL} , with the same slope as the reference line, is defined as linearity error. The magnetic field angle is varied at fixed temperatures for measurement of this linearity error. The output signal deviation from the best straight line at the given temperature is the linearity error $\Delta \phi_{lin}$. It is a function of the magnetic field angle α and the temperature of the device T_{amb} .



12.4 Microlinearity error

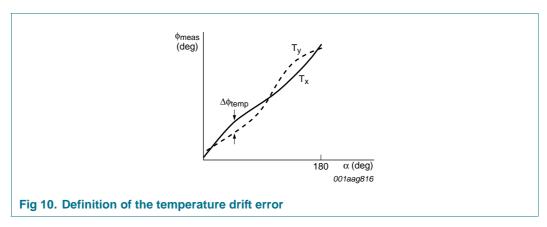
The microlinearity error $\Delta\phi_{\mu lin}$ is the device output deviation from 1°, if the magnetic field angle α is changed by $\Delta\alpha=1^{\circ}$.



12.5 Temperature drift error

The temperature drift $\Delta\phi_{temp}$ is defined as the envelope over the deviation of the angle versus the temperature range. It is considered as the pure thermal effect.

Programmable angle sensor



Equation 2 gives the mathematical description for temperature drift value $\Delta \phi_{temp}$:

$$\Delta \phi_{temp}(\alpha) = \left| \phi_{meas}(\alpha, T_x) - \phi_{meas}(\alpha, T_y) \right| \tag{2}$$

with:

 T_x : temperature for maximum ϕ_{meas} at angle α

 T_v : temperature for minimum ϕ_{meas} at angle α

The deviation from the value at room temperature $\Delta \phi_{\text{temp}}|_{\text{RT}}$ describes the temperature drift of the angle, compared to the value, which the sensor provides at room temperature:

$$\Delta \phi_{temp|RT}(\alpha, T_{amb}) = \left| \phi_{meas}(\alpha, T_{amb}) - \phi_{meas}(\alpha, T_{RT}) \right| \tag{3}$$

with:

T_{RT}: room temperature (25 °C)

12.6 Angular error

The angular error $\Delta\phi_{ang}$ is the error of angle difference measured by the sensor, if the mechanical angle deviates from α_0 to α_1 . Here α_0 and α_1 are arbitrary angles within the angular range. The angle measurement at α_0 is the initially programmed reference angle, programmed by the customer at room temperature and zero hour upon production. The angle measurement at α_1 is made at any temperature within the ambient temperature range:

$$\Delta \phi_{ang} = (\phi_{meas}(\alpha_1, T_{amb}) - \phi_{meas}(\alpha_0, T_{RT})) - (\alpha_1 - \alpha_0)$$
(4)

with:

 α_0 , α_1 : arbitrary mechanical angles within the angular range

 $\phi_{\text{meas}}(\alpha_0, T_{\text{RT}})$: programmed angle at $\alpha_0, T_{\text{RT}} = 25 \,^{\circ}\text{C}$ and zero hour upon production

 $\phi_{meas}(\alpha_1,\,T_{amb})$: angle measured by the sensor at α_1 and any temperature within T_{amb}

This error comprises non-linearity and temperature drift related to the room temperature.

Programmable angle sensor

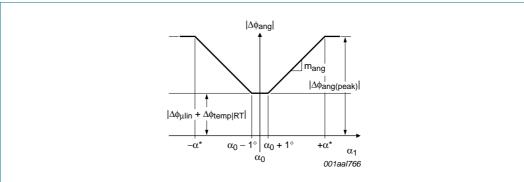


Fig 11. Envelope curve for the magnitude of angular error

Figure 11 shows the envelope curve for the magnitude of angular error $|\Delta\phi_{ang}|$ versus α_1 for all angles α_0 and all temperatures T_{amb} within the ambient temperature range. $|\Delta\phi_{ang}|$ has its minimum, if α_1 is in the range of $\pm 1^\circ$ around α_0 . Here only the microlinearity error $\Delta\phi_{\mu lin}$ and the temperature drift related to the room temperature $|\Delta\phi_{temp}|_{RT}|$ occurs. If α_1 deviates from α_0 by more than 1° in either direction, $|\Delta\phi_{ang}|$ can increase with a gradient defined by slope m_{ang} .

Angular error can be expressed by Equation 5 to Equation 8:

for
$$|\alpha_1 - \alpha_0| \leq 1^\circ$$

$$\left| \Delta \phi_{ang} \right| = \left| \Delta \phi_{\mu lin} + \Delta \phi_{temp|RT} \right| \tag{5}$$

for
$$1^{\circ} < |\alpha_1 - \alpha_0| < \alpha^*$$

$$|\Delta\phi_{ang}| = |\Delta\phi_{ulin} + \Delta\phi_{temp|RT}| + m_{ang} \times (|\alpha_1 - \alpha_0| - 1^\circ)$$
(6)

for
$$|\alpha_1 - \alpha_0| \ge \alpha^*$$

$$\left|\Delta\phi_{ang}\right| = \sqrt{(\Delta\phi_{lin})^2 + (\Delta\phi_{temp|RT})^2} \tag{7}$$

with:

$$\alpha^* = \frac{\left|\Delta\phi_{\text{ang(peak)}}\right| - \left|\Delta\phi_{\mu lin} + \Delta\phi_{temp|RT}\right|}{m_{ang}} + \alpha_0 + I^{\circ}$$
(8)

13. Programming

13.1 General description

The KMA210 provides an OWI to enable programming of the device which uses pin OUT/DATA bidirectionally.

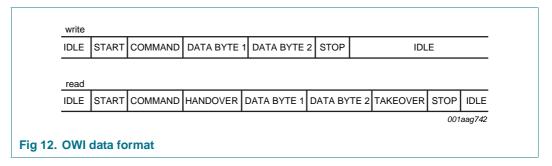
In general the device runs in analog output mode, the normal operation mode. This mode is configured by the embedded programming data and is started after a power-on reset once time t_{on} has elapsed. In this mode, the magnetic field angle is converted into the corresponding output voltage.

Programmable angle sensor

Command mode has to be entered to enable programming. In this mode, the customer can adjust all required parameters (for example zero angle and angular range) to meet the application requirements. After enabling the internal charge pump and waiting for t_{cp} the data is stored in the non-volatile memory. After changing the contents of the memory, the checksum must be recalculated and written (see Section 13.4).

In order to enter the command mode, a specific command sequence must be sent after a power-on reset and during the time slot $t_{cmd(ent)}$. The external source used to send the command sequence must overdrive the output buffer of the KMA210. In doing so it provides current I_{od} .

During communication, the KMA210 is always the slave and the external programming hardware is the master. Figure 12 illustrates the structure of the OWI data format.



The master provides the start condition, which is a rising edge after a LOW level. Then a command byte which can be either a read or a write command is sent. Depending on the command, the master or the slave has to send the data immediately after the command sequence. In the case of a read command, an additional handover or takeover bit is inserted before and after the data bytes. Each communication must be closed with a stop condition driven by the master. If the slave does not receive a rising edge for a time longer than t_{to} , a time-out condition occurs. The bus is reset to the idle state and waits for a start condition and a new command. This can be used to synchronize the device regardless of the previous state.

All communication is based on this structure (see <u>Figure 12</u>), even for entering the command mode. In this case a special write command is required, followed by the command sequence (two data bytes). The customer can access the non-volatile memory, CTRL1, TESTCTRL0 and SIGNATURE registers (described in <u>Section 13.5</u>). Only a power-on reset will leave the command mode. A more detailed description of the programming is given in the next sections.

13.2 Timing characteristics

As described in the previous section, a start and stop condition is necessary for communication. The LOW-level duration before the rising edge of the start condition is defined as t_{start} . The HIGH-level duration after the rising edge of the stop condition is defined as t_{stop} . These parameters, together with all other timing characteristics are shown in Table 14.

Programmable angle sensor

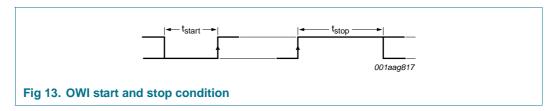
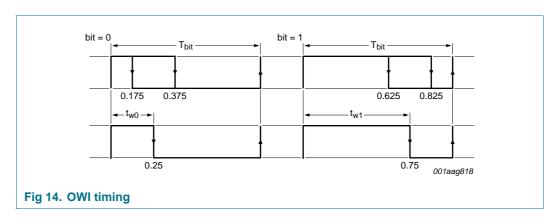


Figure 14 shows the coding of a single bit with a HIGH level of V_{IH} and a LOW level of V_{IL} . Here the pulse width t_{w1} or t_{w0} represents a logic 1 or a logic 0 of a full bit period T_{bit} , respectively.



13.3 Sending and receiving data

The master has to control the communication during sending or receiving data. The command byte defines the region, address and type of command requested by the master. In case of a read command, an additional handover or takeover bit must be inserted before and after the two data bytes (see Figure 12). However the OWI is a serial data transmission, whereas the Most Significant Byte (MSB) must be sent at first.

Table 16. Format of a command byte

7	6	5	4	3	2	1	0
CMD7	CMD6	CMD5	CMD4	CMD3	CMD2	CMD1	CMD0

Table 17. Command byte bit description

Bit	Symbol	Description
7 to 5	CMD[7:5]	region bits
		000 = 16-bit non-volatile memory
		001 to 011 = reserved
		100 = 16-bit register
		101 to 111 = reserved
4 to 1	CMD[4:1]	address bits
0	CMD0	read/write
		0 = write
		1 = read

Programmable angle sensor

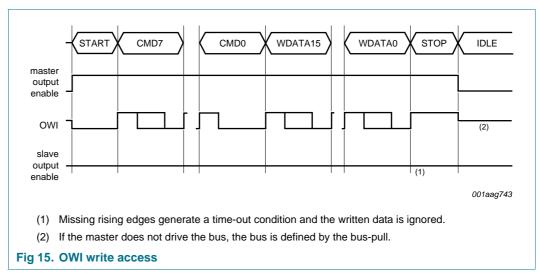
A more detailed description of all customer accessible registers is given in <u>Section 13.5</u>. Both default value and the complete command including the address and write or read request are also listed.

13.3.1 Write access

To write data to the non-volatile memory, the internal charge pump must be enabled by setting bits CP_CLOCK_EN and $WRITE_EN$ and waiting for t_{cp} . The following procedure must be performed:

- 1. Start condition: The master drives a rising edge after a LOW level
- 2. Command: The master sends a write command (CMD0 = 0)
- 3. Data: The master sends two data bytes
- 4. Stop condition: The master drives a rising edge after a LOW level

<u>Figure 15</u> shows the write access of the digital interface. The signal OWI represents the data on the bus from the master or slave. The signals: master output enable and slave output enable indicate when the master or the slave output is enabled or disabled, respectively.



Note: As already mentioned in Section 13.1, the command mode has to be entered using the write procedure. If command mode is not entered, communication is not possible and the sensor operates in normal operation mode. After changing an address, the time t_{prog} must elapse before changing another address. Finally the checksum must be recalculated and written, because the contents of the non-volatile memory have been changed (see Section 13.4).

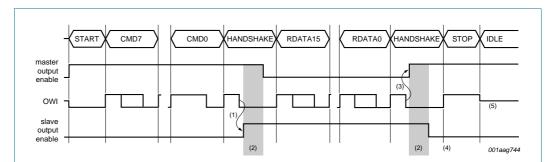
Programmable angle sensor

13.3.2 Read access

To read data from the sensor, the following procedure must be performed:

- 1. Start condition: The master drives a rising edge after a LOW level
- 2. Command: The master sends a read command (CMD0 = 1)
- 3. Handover: The master sends a handover bit, that is a logic 0 and disables the output after a three-quarter bit period
- 4. Takeover: The slave drives a LOW level after the falling edge for ttko(slv)
- 5. Data: The slave sends two data bytes
- 6. Handover: The slave sends a handover bit, that is a logic 0 and disables the output after a three-quarter bit period
- 7. Takeover: The master drives a LOW level after the falling edge for t_{tko(mas)}
- 8. Stop condition: The master drives a rising edge after a LOW level

<u>Figure 16</u> shows the read access of the digital interface. The signal OWI represents the data on the bus from the master or slave. The signals: master output enable and slave output enable indicate when the master or the slave output is enabled or disabled, respectively.



- (1) Duration of LOW level for slave takeover $t_{tko(slv)}$.
- (2) There is an overlap in the output enables of master and slave, because both drive a LOW level. However this ensures the independency from having a pull-up or pull-down on the bus. In addition it improves the EMC robustness, because all levels are actively driven.
- (3) Duration of LOW level for master takeover t_{tko(mas)}.
- (4) If the master does not take over and a pull-up exists, the stop condition is generated by the pull-up. Otherwise a time-out is generated if there is a pull-down and the slave waits for a rising edge as start condition.
- (5) If the master does not drive the bus, the bus is defined by the bus-pull.

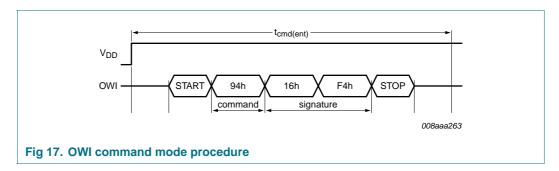
Fig 16. OWI read access

Programmable angle sensor

13.3.3 Entering the command mode

After a power-on reset, the sensor provides a time slot $t_{cmd(ent)}$ for entering the command mode. A specific command sequence has to be sent (see Figure 17). If command mode is not entered, the sensor starts in the normal operation mode. However the signature can be written by the master if the sensor switches to diagnostic mode.

During the command mode sequence, the analog output is enabled. The external programming hardware has to overdrive the output with current I_{od}. If command mode is activated, the analog output is disabled and pin OUT/DATA operates as a digital interface.



13.4 Cyclic redundancy check

As already mentioned in <u>Section 7</u>, there is an 8-bit checksum for the non-volatile memory data. To calculate this value, the CRC needs to be generated with the MSB of the memory data word at first over all corresponding addresses in increasing order.

All addresses from 8h to Fh must be read out for calculating the checksum. The Least Significant Byte (LSB) of address Fh which contains the previous checksum must be overwritten with 0h before the calculation can be started.

Finally, the internal charge pump has to be enabled for programming by setting bits CP_CLOCK_EN and $WRITE_EN$ (see Section 13.5.1) and waiting for t_{cp} .

The generator polynomial for the calculation of the checksum is:

$$G(x) = x^8 + x^2 + x + 1 (9)$$

With a start value of FFh and the data bits are XOR at the x⁸ point.

Programmable angle sensor

13.4.1 Software example in C

```
#include <stdio.h.>
1
    // calc_crc accepts unsigned 16-bit data in data
3
     int calc crc(int crc, unsigned int data)
5
6
           const int gpoly = 0x107; // generator polynomial
                                      //index variable
7
           for (i = 15; i >= 0; i--)
9
                                      //shift left
                crc <<= 1;
10
11
                crc |= (int) ((data & (1u<<i))>>i);
12
                // XOR of with generator polynomial when MSB(9) = HIGH
13
                if (crc & 0x100) crc ^= gpoly;
14
15
           return crc;
16
17
     int main(void)
18
     {
           int crc, crc_res, i;
19
20
           // 8 LSB are CRC field filled with 0
           unsigned int data_seq[] = {0x0000, 0xFFC1, 0x0400, 0x0100,
2.1
                                      0x1300, 0x0000, 0x0000, 0x0000);
22
23
          // calculate checksum over all data
24
           crc = 0xFF;
                                      // start value of crc register
25
          printf("Address\tValue\n");
26
           for (i = 0; i <= 7; i++)
2.7
                printf("0x%1X\t0x%04X\n", i, data_seq[i]);
28
29
                crc = calc_crc(crc, data_seq[i]);
30
31
           crc_res = crc;
                                      // crc_res = 0xA9
32
           printf("\nChecksum\n0x%02X\n", crc_res);
33
           // check procedure for above data sequence
34
          crc = 0xFF;
35
          for (i = 0; i <= 6; i++)
36
                crc = calc_crc(crc, data_seq[i]);
37
          // last word gets crc inserted
38
          crc = calc_crc(crc, data_seg[i] | crc_res);
39
          printf("\nCheck procedure for data sequence: must be 0x00 is 0x%02X.\n",crc);
40
          return 1;
41
```

The checksum of this data sequence is A9h.

Programmable angle sensor

13.5 Registers

13.5.1 Command registers

To enter the command mode, the signature given in <u>Table 18</u> must be written into the specific register using the OWI. This must be done as described in <u>Section 13.3.3</u>, with a write command, followed by the signature, but after a power-on reset and not later than $t_{cmd(ent)}$.

Table 18. Command registers

	Command reg	Bit	Access	Eiold	Description
Command write/read	Register	DIL	Access	rieia	Description
82h/83h	CTRL1	15	R	IN_DIAG_MODE	shows if there is a diagnostic condition present; this bit is not affected by the setting of register field FORCE_DIAG_OFF
		14	W	FORCE_DIAG_OFF	force diagnostic mode off; default: 0b
		13	-	-	reserved
		12	R	LOW_VOLTAGE_DET	low voltage condition detected
		11	R/W	CP_CLOCK_EN	charge pump clock enabled (must be set after setting write enable signal for writing to non-volatile memory); default: 0b
		10 and 9	-	-	reserved
		8	R	ERR_CORRECT	single-bit error of non-volatile memory has been detected and corrected; updated every memory readout; remains set until the diagnostic condition disappears and a power-on reset is done
		7	R	UNCORR_ERR	double-bit error of non-volatile memory has been detected; updated every memory readout; remains set until the diagnostic condition disappears and a power-on reset is done
		6	R	MAGNET_LOSS_DET	magnet-loss detected; bit remains set until the diagnostic condition disappears and a power-on reset is done; magnet-loss detection must be enabled for entering diagnostic mode
		5	R	BROKEN_BOND_DET	broken bond wire detected; bit remains set until the diagnostic condition disappears and a power-on reset is done
		4	R	CRC_BAD	checksum error detected; updated every start-up
		3 to 0	-	-	reserved
94h/-	SIGNATURE	15 to 0	W	SIGNATURE	write signature 16F4h within t _{cmd(ent)} to enter command mode; see <u>Section 13.3.3</u> for more details
96h/97h	TESTCTRL0	15 to 12	-	-	reserved
		11	W	WRITE_EN	write enable signal; must be set before writing to non-volatile memory; default: 0b
		10 to 0	-	-	reserved
					_

Programmable angle sensor

13.5.2 Non-volatile memory registers

The device includes several internal registers which are used for customization and identification.

The initial signature allows read access to all areas but only write access to customer registers. Write accesses to reserved areas are ignored. Since these registers are implemented as non-volatile memory cells, writing to the registers needs a specific time t_{prog} after each write access to complete.

As there is no check for the programming time, the user must make sure no other accesses to the non-volatile memory are made during the programming cycle. The non-volatile memory must not be addressed during the time t_{prog} .

Note: Before data can be stored in the non-volatile memory, the internal charge pump has to be switched on for the programming duration by setting register CTRL1, bit 11 CP_CLOCK_EN and register TESTCTRL0, bit 11 WRITE_EN. Register addresses 8h to Fh have to be read out and consulted to calculate the checksum.

Table 19. Non-volatile memory registers

Address	Command write/read	Register	Bit	Description	Default MSB/LSB
0h	-/01h	reserved	-	addresses are reserved for calibration purposes	<u>[1]</u>
1h	-/03h				
2h	-/05h				
3h	-/07h				
4h	-/09h				
5h	-/0Bh				
6h	-/0Dh				
7h	-/0Fh				
8h	10h/11h	ZERO_ANGLE	15 to 0	mechanical zero degree position; see Table 20	00h/00h
9h	12h/13h	ANG_RNG_MULT_MSB	15 to 6	CLAMP_SW_ANGLE; when the measured angle is bigger than CLAMP_SW_ANGLE the output switches to CLAMP_LO for a positive slope; see Table 25	FFh/C1h
			5 to 0	ANG_RNG_MULT_MSB; most significant bits of the angular range multiplicator; see Table 23	
Ah	14h/15h	ANG_RNG_MULT_LSB	15 and 14	DIAGNOSTIC_LEVEL; diagnostic level behavior of the analog output; see Table 24	04h/00h
				00b — active LOW (in lower diagnostic range) with driver strength of the analog output	
				01b — active HIGH (in upper diagnostic range) with driver strength of the analog output	
				10b — reserved	
				11b — reserved	
			13	SLOPE_DIR; slope of analog output	
				0b — rising (not inverted)	
				1b — falling (inverted)	
			12 to 0	ANG_RNG_MULT_LSB; least significant bits of the angular range multiplicator	

Programmable angle sensor

Table 19. Non-volatile memory registers ...continued

Address	Command write/read	Register	Bit	Description	Default MSB/LSB
Bh	16h/17h	CLAMP_LO	15	0b — reserved	01h/00h
			14 and 13	undefined ^[2]	
			12 to 0	lower clamping level; see <u>Table 21</u>	
Ch	18h/19h	CLAMP_HI	15 to 13	undefined[2]	13h/00h
			12 to 0	upper clamping level; see <u>Table 22</u>	
Dh	1Ah/1Bh	ID_LO	15 to 0	lower 16 bits of identification code	00h/00h
Eh	1Ch/1Dh	ID_HI	15 to 0	upper 16 bits of identification code	00h/00h
Fh	1Eh/1Fh	CTRL_CUST	15	LOCK; irreversible write protection of non-volatile memory	00h/[1]
			11 to 0	1b — enabled	
			14 to 8	MAGNET_LOSS; magnet-loss detection 00h — disabled	
				49h — enabled	
			7 to 0	CRC; checksum (see Section 13.4)	

^[1] Variable and individual for each device.

Table 20. ZERO_ANGLE - mechanical zero degree position (address 8h) bit allocation

Data format: unsigned fixed point; resolution: 2⁻¹⁶.

Bit																
Value	2-1	2-2	2-3	2-4	2-5	2-6	2-7	2-8	2 ⁻⁹	2-10	2-11	2-12	2-13	2-14	2 ⁻¹⁵	2-16

Mechanical angular range $0000h = 0^{\circ}$ to FFFFh = $180^{\circ} - 1$ LSB.

Examples:

- Mechanical zero angle 0° = 0000h
- Mechanical zero angle 10° = 0E38h
- Mechanical zero angle 45° = 4000h

Table 21. CLAMP_LO - lower clamping level (address Bh) bit allocation

Data format: unsigned integer (DAC values 256 to 4864); resolution: 20.

Bit	15	14	13	12	11	10	9	8	7	6	5	4	3	2	1	0
Value	0	U <u>[1]</u>	U <u>[1]</u>	2 ¹²	2 ¹¹	2 ¹⁰	2 ⁹	2 ⁸	27	2 ⁶	2 ⁵	2^{4}	2 ³	2 ²	21	20

[1] Undefined; must be written as zero for default and may return any value when read.

Values 0 to 255 are reserved. It is not permitted to use such values.

Examples:

- 100 %V_{DD} = 5120 (reserved)
- 10 %V_{DD} = 512
- 5 %V_{DD} = 256

KMA210

^[2] Undefined; must be written as zero for default.

Programmable angle sensor

Table 22. CLAMP_HI - upper clamping level (address Ch) bit allocation

Data format: unsigned integer (DAC values 256 to 4864); resolution: 20.

Bit	15	14	13	12	11	10	9	8	7	6	5	4	3	2	1	0
Value	U <u>[1]</u>	U <u>[1]</u>	U <u>[1]</u>	2 ¹²	2 ¹¹	2 ¹⁰	2 ⁹	2 ⁸	27	2 ⁶	2 ⁵	2 ⁴	2 ³	22	21	20

[1] Undefined; must be written as zero for default and may return any value when read.

Values 4865 to 5120 are reserved. It is not permitted to use such values.

Examples:

- 100 %V_{DD} = 5120 (reserved)
- 95 %V_{DD} = 4864
- 90 %V_{DD} = 4608

Table 23. ANG_RNG_MULT_MSB - most significant bits of angular range multiplicator (address 9h) bit allocation Data format: unsigned fixed point; resolution: 2⁻¹.

Bit	15	14	13	12	11	10	9	8	7	6	5	4	3	2	1	0
Value	CLAMP_SW_ANGLE							2 ⁴	2 ³	2 ²	2 ¹	2 ⁰	2-1			

$$ANG_{\text{RNG_MULT}} = \frac{\text{CLAMP_HI} - \text{CLAMP_LO}}{8192} \times \frac{180^{\circ}}{ANGULAR \text{ RANGE}}$$
 (10)

Examples:

- $ANG_RNG_MULT = \frac{4864 256}{8192} \times \frac{180^\circ}{180^\circ} = 0.5625$
- ANG_RNG_MULT = $\frac{4864 256}{8192} \times \frac{180^{\circ}}{90^{\circ}} = 1.125$

Table 24. ANG_RNG_MULT_LSB - least significant bits of angular range multiplicator (address Ah) bit allocation Data format: unsigned fixed point; resolution: 2⁻¹⁴.

																0
Value	V	<u>1]</u>	V <u>[1]</u>	2-2	2-3	2-4	2-5	2-6	2^{-7}	2-8	2-9	2-10	2-11	2-12	2-13	2-14

[1] Variable; depending on the setting of diagnostic level and slope of analog output.

$$ANG_{\text{RNG_MULT}} = \frac{\text{CLAMP_HI} - \text{CLAMP_LO}}{8192} \times \frac{180^{\circ}}{ANGULAR \text{ RANGE}}$$
(11)

Table 25. CLAMP_SW_ANGLE - clamp switch angle (address 9h) bit allocation

Data format: unsigned fixed point; resolution: 2^{-10} .

Bit	15	14	13	12	11	10	9	8	7	6	5	4	3	2	1	0
Value	2-1	2-2	2-3	2-4	2-5	2-6	2-7	2-8	2-9	2-10		ANG	_RNG_	MULT_	MSB	

Mechanical angular range $0000h = 0^{\circ}$ to 3FFh = $180^{\circ} - 1$ LSB.

$$CLAMP_SW_ANGLE = \frac{1}{2} \times \left(1 + \frac{CLAMP_HI - CLAMP_LO}{8192} \times \frac{1}{ANG_RNG_MULT} \right)$$
 (12)

If the magnetic field angle is larger than the CLAMP_SW_ANGLE, the output switches to CLAMP_LO for a positive slope. The value of CLAMP_SW_ANGLE can be calculated from other non-volatile memory constants but must be programmed.

KMA210

Programmable angle sensor

14. Electromagnetic compatibility

EMC is verified in an independent and certified test laboratory.

14.1 Emission (CISPR 25)

Tests according to CISPR 25 were fulfilled.

14.1.1 Conducted radio disturbance

Test of the device according to CISPR 25, third edition (2008-03), Chapter 6.2.

Classification level: 5.

14.1.2 Radiated radio disturbance

Test of the device according to CISPR 25, third edition (2008-03), Chapter 6.4.

Classification level: 5 (without addition of 6 dB in FM band).

14.2 Radiated disturbances (ISO 11452-1 third edition (2005-02), ISO 11452-2, ISO 11452-4 and ISO 11452-5)

The common understanding of the requested function is that an effect is tolerated as described in <u>Table 26</u> during the disturbance. The reachable values are setup dependent and may differ from the final application.

Table 26. Failure condition for radiated disturbances

Parameter	Comment	Min	Max	Unit
Variation of output signal in analog output mode	value measured relative to the output at test start	-	±0.9	%V _{DD}

14.2.1 Absorber lined shielded enclosure

Tests according to ISO 11452-2, second edition (2004-11), were fulfilled.

Test level: 200 V/m; extended up to 10 GHz.

State: A.

14.2.2 Bulk-current injection

Tests according to ISO 11452-4, third edition (2005-04), were fulfilled.

Test level: 200 mA.

State: A.

14.2.3 Strip line

Tests according to ISO 11452-5, second edition (2002-04), were fulfilled.

Test level: 200 V/m; extended up to 1 GHz.

State: A.

Programmable angle sensor

14.2.4 Immunity against mobile phones

Tests according to ISO 11452-2, second edition (2004-11), were fulfilled.

State: A.

Definition of Global System for Mobile Communications (GSM) signal:

- Pulse modulation: per GSM specification (217 Hz; 12.5 % duty cycle)
- Modulation grade: ≥ 60 dB
- Sweep: linear 800 MHz to 3 GHz (duration 10 s at 890 MHz, 940 MHz and 1.8 GHz band)
- Antenna polarization: vertical, horizontal
- Field strength: 200 V/m during on-time [calibration in Continuous Wave (CW)]

In deviation of ISO 11452-2 a GSM signal (definition see above) instead of an AM signal was used.

14.3 Electrical transient transmission by capacitive coupling [ISO 7637-3, second edition (2007-07)]

The common understanding of the requested function is that an effect is tolerated as described in Table 27 during the disturbance.

Table 27. Failure condition for electrical transient transmission

Parameter	Comment	Min	Max	Unit
Variation of output signal in analog output mode	value measured relative to the output at test start	-	±0.9	%V _{DD}

Tests according to ISO 7637-3 were fulfilled.

Test level: IV (for 12 V electrical system).

Classification level: B for pulse Fast a, B for pulse Fast b.

Programmable angle sensor

15. ElectroStatic Discharge (ESD)

15.1 Human body model (AEC-Q100-002)

The KMA210 must not be damaged at 8 kV, according to the human body model at 100 pF and 1.5 k Ω . This protection is ensured at all external pins (OUT/DATA, V_{DD} and GND).

Classification level: H3B.

Furthermore, all interconnects (pins between package head and package body) must not be damaged at 2 kV.

Classification level: H2.

15.2 Human metal model (ANSI/ESD SP5.6-2009)

The KMA210 must not be damaged at 8 kV, according to the human metal model at 150 pF and 330 Ω inside the ESD gun. This test utilizes waveforms of the IEC 61000-4-2 standard on component level. The contact discharge will be applied in an unsupplied state at pins OUT/DATA and V_{DD} referred to GND which is connected directly to the ground plane.

Test setup: A.

Test level: 5.

15.3 Machine model (AEC-Q100-003)

The KMA210 must not be damaged at 400 V, according to the machine model. This protection is ensured at all external pins (OUT/DATA, V_{DD} and GND).

Classification level: M4.

Furthermore, all interconnects (pins between package head and package body) must not be damaged at 200 V.

Classification level: M3.

All pins have latch-up protection.

15.4 Charged-device model (AEC-Q100-011)

The KMA210 must not be damaged at 750 V, according to the charged-device model. This protection is ensured at all external pins (OUT/DATA, V_{DD} and GND).

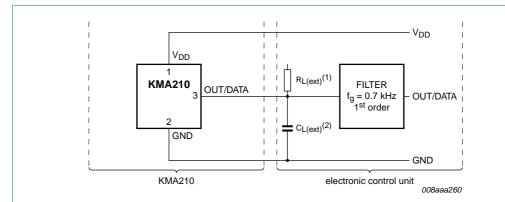
Classification level: C4.

Furthermore, all interconnects (pins between package head and package body) must not be damaged at 500 V.

Classification level: C3B.

Programmable angle sensor

16. Application information



- (1) Power-loss detection is only possible with a load resistance within the specified range connected to the supply or ground line.
- (2) The load capacitance between ground and analog output can be used to improve the electromagnetic immunity of the device. A blocking capacitance to suppress noise on the supply line of the device is integrated into the package and thus not required externally.

Fig 18. Application diagram of KMA210

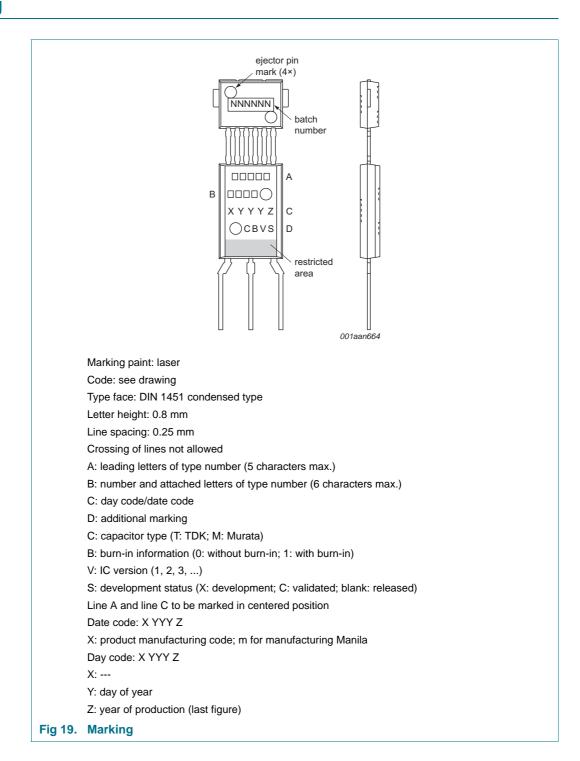
17. Test information

17.1 Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q100 Rev-G - Failure mechanism based stress test qualification for integrated circuits*, and is suitable for use in automotive applications.

Programmable angle sensor

18. Marking



19. Terminals

Lead frame material: CuZr with 99.9 % Cu and 0.1 % Zr.

Programmable angle sensor

20. Package outline

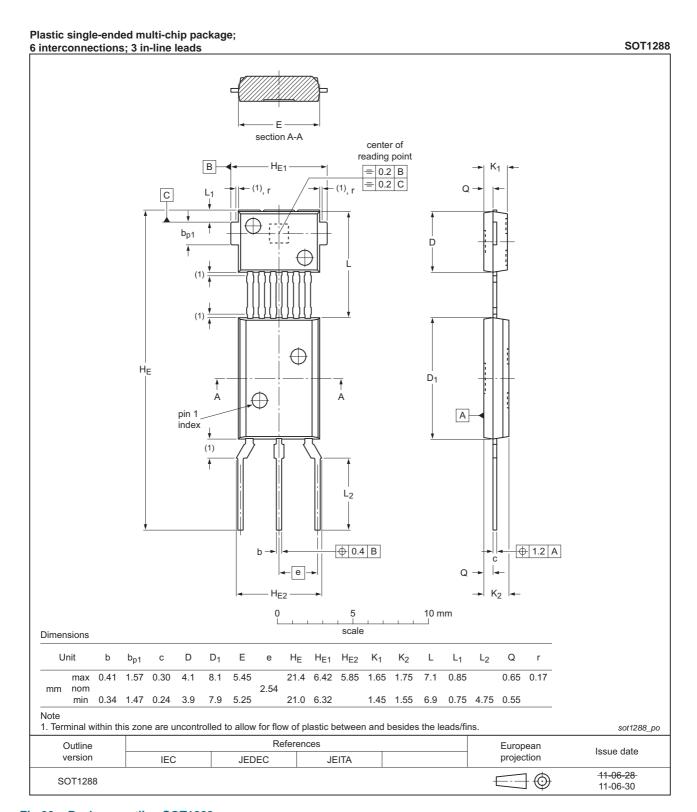


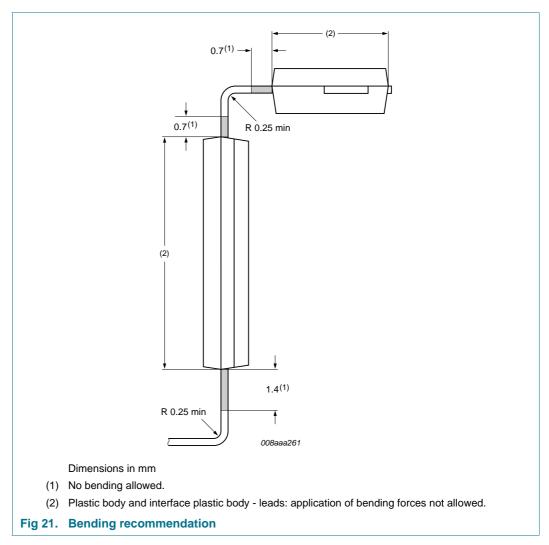
Fig 20. Package outline SOT1288

A210 All information provided in this document is subject to legal disclaimers.

© NXP B.V. 2011. All rights reserved.

Programmable angle sensor

21. Handling information



22. Solderability information

The solderability qualification is according to AEC-Q100 Rev-G. Recommended soldering process for leaded devices is wave soldering. The maximum soldering temperature is 260 °C for maximum 5 s. Device terminals shall be compatible with laser and electrical welding. The device is reflow capable.

KMA210 NXP Semiconductors

Programmable angle sensor

23. Revision history

Table 28. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes						
KMA210 v.2	20111207	Product data sheet	-	KMA210 v.1						
Modifications:	Table 6 "Dia	<u>Table 6 "Diagnostic behavior"</u> : Power-loss duration changed								
	Section 19 ⁶	Section 19 "Terminals": Lead finish information removed								
KMA210 v.1	20110630	Product data sheet	-	-						

Programmable angle sensor

24. Legal information

24.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design
- [2] The term 'short data sheet' is explained in section "Definitions"
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

24.2 Definitions

Draft — The document is a draft version only. The content is still under internal review and subject to formal approval, which may result in modifications or additions. NXP Semiconductors does not give any representations or warranties as to the accuracy or completeness of information included herein and shall have no liability for the consequences of use of such information.

Short data sheet — A short data sheet is an extract from a full data sheet with the same product type number(s) and title. A short data sheet is intended for quick reference only and should not be relied upon to contain detailed and full information. For detailed and full information see the relevant full data sheet, which is available on request via the local NXP Semiconductors sales office. In case of any inconsistency or conflict with the short data sheet, the full data sheet shall prevail.

Product specification — The information and data provided in a Product data sheet shall define the specification of the product as agreed between NXP Semiconductors and its customer, unless NXP Semiconductors and customer have explicitly agreed otherwise in writing. In no event however, shall an agreement be valid in which the NXP Semiconductors product is deemed to offer functions and qualities beyond those described in the Product data sheet.

24.3 Disclaimers

Limited warranty and liability — Information in this document is believed to be accurate and reliable. However, NXP Semiconductors does not give any representations or warranties, expressed or implied, as to the accuracy or completeness of such information and shall have no liability for the consequences of use of such information.

In no event shall NXP Semiconductors be liable for any indirect, incidental, punitive, special or consequential damages (including - without limitation - lost profits, lost savings, business interruption, costs related to the removal or replacement of any products or rework charges) whether or not such damages are based on tort (including negligence), warranty, breach of contract or any other legal theory.

Notwithstanding any damages that customer might incur for any reason whatsoever, NXP Semiconductors' aggregate and cumulative liability towards customer for the products described herein shall be limited in accordance with the *Terms and conditions of commercial sale* of NXP Semiconductors.

Right to make changes — NXP Semiconductors reserves the right to make changes to information published in this document, including without limitation specifications and product descriptions, at any time and without notice. This document supersedes and replaces all information supplied prior to the publication hereof.

Suitability for use in automotive applications — This NXP Semiconductors product has been qualified for use in automotive applications. Unless otherwise agreed in writing, the product is not designed,

authorized or warranted to be suitable for use in life support, life-critical or safety-critical systems or equipment, nor in applications where failure or malfunction of an NXP Semiconductors product can reasonably be expected to result in personal injury, death or severe property or environmental damage. NXP Semiconductors accepts no liability for inclusion and/or use of NXP Semiconductors products in such equipment or applications and therefore such inclusion and/or use is at the customer's own risk.

Applications — Applications that are described herein for any of these products are for illustrative purposes only. NXP Semiconductors makes no representation or warranty that such applications will be suitable for the specified use without further testing or modification.

Customers are responsible for the design and operation of their applications and products using NXP Semiconductors products, and NXP Semiconductors accepts no liability for any assistance with applications or customer product design. It is customer's sole responsibility to determine whether the NXP Semiconductors product is suitable and fit for the customer's applications and products planned, as well as for the planned application and use of customer's third party customer(s). Customers should provide appropriate design and operating safeguards to minimize the risks associated with their applications and products.

NXP Semiconductors does not accept any liability related to any default, damage, costs or problem which is based on any weakness or default in the customer's applications or products, or the application or use by customer's third party customer(s). Customer is responsible for doing all necessary testing for the customer's applications and products using NXP Semiconductors products in order to avoid a default of the applications and the products or of the application or use by customer's third party customer(s). NXP does not accept any liability in this respect.

Limiting values — Stress above one or more limiting values (as defined in the Absolute Maximum Ratings System of IEC 60134) will cause permanent damage to the device. Limiting values are stress ratings only and (proper) operation of the device at these or any other conditions above those given in the Recommended operating conditions section (if present) or the Characteristics sections of this document is not warranted. Constant or repeated exposure to limiting values will permanently and irreversibly affect the quality and reliability of the device.

Terms and conditions of commercial sale — NXP Semiconductors products are sold subject to the general terms and conditions of commercial sale, as published at http://www.nxp.com/profile/terms, unless otherwise agreed in a valid written individual agreement. In case an individual agreement is concluded only the terms and conditions of the respective agreement shall apply. NXP Semiconductors hereby expressly objects to applying the customer's general terms and conditions with regard to the purchase of NXP Semiconductors products by customer.

No offer to sell or license — Nothing in this document may be interpreted or construed as an offer to sell products that is open for acceptance or the grant, conveyance or implication of any license under any copyrights, patents or other industrial or intellectual property rights.

KMA210

All information provided in this document is subject to legal disclaimers.

© NXP B.V. 2011. All rights reserved.

Programmable angle sensor

Export control — This document as well as the item(s) described herein may be subject to export control regulations. Export might require a prior authorization from competent authorities.

24.4 Trademarks

Notice: All referenced brands, product names, service names and trademarks are the property of their respective owners.

25. Contact information

For more information, please visit: http://www.nxp.com

For sales office addresses, please send an email to: salesaddresses@nxp.com

KMA210 NXP Semiconductors

Programmable angle sensor

26. Contents

1 1.1	Product profile	1	14.2	Radiated disturbances (ISO 11452-1 third edition (2005-02), ISO 11452-2, ISO 11452-4	
1.2	Features and benefits	1		and ISO 11452-5)	
2	Pinning information	2	14.2.1	Absorber lined shielded enclosure	
3	Ordering information	2	14.2.2	Bulk-current injection	
4	Functional diagram	3	14.2.3 14.2.4	Strip line	
5	Functional description		14.2.4	Electrical transient transmission by capacitive	20
5.1	Angular measurement directions		14.3	coupling [ISO 7637-3, second edition	
6	Analog output			(2007-07)]	28
7	Diagnostic features		15	ElectroStatic Discharge (ESD)	
7 .1	CRC and EDC supervision		15.1	Human body model (AEC-Q100-002)	
7.2	Magnet-loss detection		15.2	Human metal model (ANSI/ESD SP5.6-2009)	
7.3	Power-loss detection		15.3	Machine model (AEC-Q100-003)	
7.4	Broken bond wire detection	-	15.4	Charged-device model (AEC-Q100-011)	
7.5	Low supply voltage detection and overvoltage		16	Application information	30
	protection	7	17	Test information	30
8	Limiting values	8	17.1	Quality information	30
9	Recommended operating conditions	9	18	Marking	
10	Thermal characteristics	9	19	Terminals	31
11	Characteristics	9	20	Package outline	32
12	Definition of errors	13	21	Handling information	
12.1	General	13	22	Solderability information	
12.2	Hysteresis error	13	23	Revision history	
12.3		14	24	Legal information	
12.4	,,	14	24.1	Data sheet status	
12.5	Temperature drift error		24.1	Definitions	
12.6	Angular error		24.3	Disclaimers	
13	Programming		24.4	Trademarks	
13.1	General description		25	Contact information	
13.2		17	26	Contents	
13.3	containing annual containing a	18	20	Contents	31
13.3.1		19			
13.3.2		20			
13.3.3	Entering the command mode				
13.4 13.4.1	Cyclic redundancy check				
13.4.1	Registers				
13.5.1	Command registers				
13.5.2	Non-volatile memory registers				
14	Electromagnetic compatibility				
14.1	Emission (CISPR 25)				
14.1.1	Conducted radio disturbance				
14.1.2	Radiated radio disturbance				

Please be aware that important notices concerning this document and the product(s) described herein, have been included in section 'Legal information'.